

Diagonal 14.0 mm (Type 1/1.1) CMOS solid-state Image Sensor with Square Pixel for Monochrome Cameras

## Description

The IMX565-AAMJ is a diagonal 14.0 mm (Type 1/1.1) CMOS active pixel type solid-state image sensor with a square pixel array and 12.41 M effective pixels. This chip features a global shutter with variable charge-integration time. This chip operates with analog 3.3 V, 2.9 V, digital 1.1 V, and interface 1.8 V quadruple power supply. High sensitivity and low dark current characteristics are achieved.

(Applications: FA cameras, ITS cameras)

## Features

- ◆ CMOS active pixel type dots
- ◆ Built-in timing adjustment circuit, H/V driver and serial communication circuit
- ◆ Global shutter function
- ◆ Input frequency 37.125 MHz / 74.25 MHz / 54 MHz
- ◆ Number of recommended recording pixels: 4096 (H) × 3000 (V) approx. 12.28 M pixels
- ◆ Readout mode
  - All-pixel scan mode
  - Vertical / Horizontal 1/2 Subsampling mode
  - 2 × 2 FD binning mode
  - ROI mode
  - Vertical / Horizontal - Normal / Inverted readout mode
- ◆ Readout rate
  - Maximum frame rate in
  - All-pixel scan mode: 8 bit 42.6 frame/s, 10 bit 34.6 frame/s, 12 bit 29.2 frame/s
- ◆ Pulse Output Function
  - The monitor output for Exposure period
  - Programmable pulse output
- ◆ 8-bit / 10-bit / 12-bit A/D converter
- ◆ CDS / PGA function
  - 0 dB to 24 dB: Analog Gain (0.1 dB step)
  - 24.1 dB to 48 dB: Analog Gain: 24 dB + Digital Gain: 0.1 dB to 24 dB (0.1 dB step)
- ◆ I/O interface
  - CSI-2 serial data output (2 Lane / 4 Lane) (1188 / 891 / 594 Mbps per ch)
- ◆ Recommended lens F number: 2.8 or more (Close side)

## Pregius S

\* Pregius S is a registered trademark or trademark of Sony Group Corporation or its affiliates. Pregius S is a global shutter sensor technology for active pixel-type CMOS image sensors. By stacking the signal processing on the back illuminated type CMOS Image Sensor it realizes small chip size and high sensitivity, whilst using the high picture quality global shutter pixel technology of Pregius.

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## Device Structure

◆ CMOS image sensor		
◆ Image size	Diagonal 14.0 mm (Type 1/1.1) Approx. 12.41 M pixels	
◆ Total number of pixels	4128 (H) × 3072 (V)	Approx. 12.68 M pixels
◆ Number of effective pixels	4128 (H) × 3008 (V)	Approx. 12.41 M pixels
◆ Number of active pixels	4128 (H) × 3008 (V)	Approx. 12.41 M pixels
◆ Number of recommended recording pixels	4096 (H) × 3000 (V)	Approx. 12.28 M pixels
◆ Unit cell size	2.74 μm (H) × 2.74 μm (V)	
◆ Optical black	Horizontal (H) direction: Front 0 pixel, rear 0 pixel	
	Vertical (V) direction: Front 64 pixels, rear 0 pixel	
◆ Package	230 pin LGA	20.0 mm (H) × 16.8 mm (V)

## Image Sensor Characteristics

(T<sub>j</sub> = 60 °C)

Item		Value	Remarks
Sensitivity	Typ.	14510 Digit/lx/s	
Saturation signal	Min.	4094 Digit	

## Basic Drive Mode

Drive mode	Recommended number of recording pixels	Maximum frame rate [frame/s]	Output interface	ADC [bit]
All pixel	4096 (H) × 3000 (V) approx. 12.28 M pixels	42	CSI-2	8
		34	CSI-2	10
		29	CSI-2	12
Vertical / Horizontal 1/2 subsampling	2048 (H) × 1500 (V) approx. 3.07 M pixels	152	CSI-2	8
		126	CSI-2	10
		107	CSI-2	12
2 × 2 FD binning mode	2048 (H) × 1500 (V) approx. 3.07 M pixels	152	CSI-2	8
		126	CSI-2	10
		107	CSI-2	12

